

May 2014





180V NPN SMALL SIGNAL TRANSISTOR IN SOT323

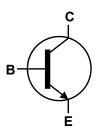
Features

- **Epitaxial Planar Die Construction**
- Ultra-Small Surface Mount Package
- Complementary NPN Type: MMST5401
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

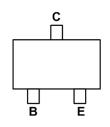
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (approximate)









Top View Pin-Out

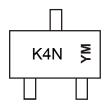
Ordering Information (Notes 4 & 5)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
MMST5551-7-F	AEC-Q101	K4N	7	8	3,000
MMST5551Q-7-F	Automotive	K4N	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K4N = Product Type Marking Code YM = Date Code Marking Y or Y = Year (ex: A = 2013) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

-													
I	Year	2010		2011	2012		2013	2014		2015	2016		2017
	Code	Х		Υ	Z		Α	В		С	D		E
Ī	Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
ſ	Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Continuous Collector Current	Ic	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	625	°C/W	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	V _{CBO}	180	_	V	$I_{C} = 100 \mu A, I_{E} = 0$	
Collector-Emitter Breakdown Voltage	V_{CEO}	160	_	V	$I_C = 1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	V _{EBO}	6.0	_	V	$I_E = 10\mu A, I_C = 0$	
Collector Cutoff Current	1		50	nA	V _{CB} = 120V, I _E = 0	
Collector Cutoff Current	I _{CBO}	_	30	μΑ	$V_{CB} = 120V$, $I_{E} = 0$, $T_{A} = +100$ °C	
Emitter Cutoff Current	I _{EBO}	_	50	nA	$V_{EB} = 4.0V, I_C = 0$	
ON CHARACTERISTICS (Note 8)						
		80	_		$I_C = 1.0 \text{mA}$, $V_{CE} = 5.0 \text{V}$	
DC Current Gain	h _{FE}	80 30	250	_	$I_C = 10 \text{mA}, V_{CE} = 5.0 \text{V}$	
		30	0.15		$I_C = 50 \text{mA}, V_{CE} = 5.0 \text{V}$ $I_C = 10 \text{mA}, I_B = 1.0 \text{mA}$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.20	V	$I_{\rm C} = 50 \text{mA}, I_{\rm B} = 5.0 \text{mA}$	
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	1.0	V	$I_C = 10mA, I_B = 1.0mA$	
	V BE(SAT)		1.0		$I_{\rm C} = 50 \text{mA}, I_{\rm B} = 5.0 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS				,		
Output Capacitance	C _{obo}	_	6.0	pF	$V_{CB} = -10V$, $f = 1.0MHz$, $I_E = 0$	
Small Signal Current Gain	h _{fe}	50	250	_	$V_{CE} = 10V, I_{C} = 1.0mA,$	
oman dignar danting dant	riie		200		f = 1.0kHz	
Current Gain-Bandwidth Product	f _T	100	300	MHz	$V_{CE} = 10V, I_{C} = 10mA,$ f = 100MHz	
Noise Figure	NF	_	8.0	dB	V_{CE} = 5.0V, I_{C} = 200 μ A, R_{S} =1.0 Ω , f = 1.0kHz	

Notes:

- 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.
- 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

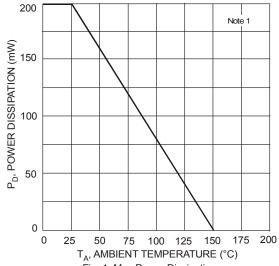
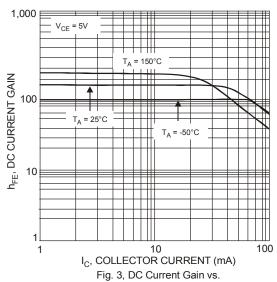
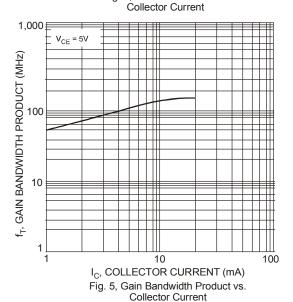


Fig. 1, Max Power Dissipation vs.
Ambient Temperature





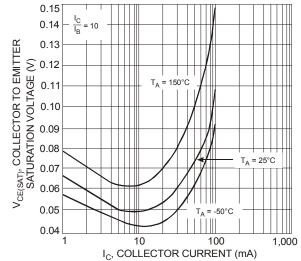
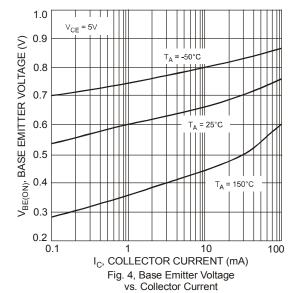


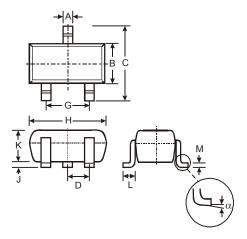
Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current





Package Outline Dimensions

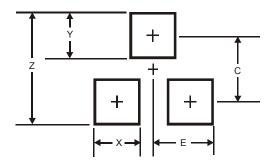
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT323						
Dim	Min	Max	Тур				
Α	0.25	0.40	0.30				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D	-	-	0.65				
G	1.20	1.40	1.30				
Н	1.80	2.20	2.15				
J	0.0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
М	0.10	0.18	0.11				
α	0°	8°	-				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
X	0.7
Y	0.9
С	1.9
F	1.0

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

May 2014



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